

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,226,513 B2
APPLICATION NO. : 10/645911
DATED : June 5, 2007
INVENTOR(S) : Hisatsugu Kurita et al.

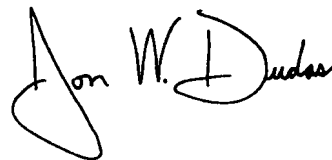
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It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 10, line 1 should read as --oxidizing a silicon wafer annealed under--

Signed and Sealed this

Eighteenth Day of September, 2007

A handwritten signature in black ink, appearing to read "Jon W. Dudas". The signature is stylized with a large, looped initial "J" and a cursive "Dudas".

JON W. DUDAS
Director of the United States Patent and Trademark Office